QL

Nch 30V 4.5A Small Signal MOSFET

Outline
SOT-457T

SC-95

TSMT6

V _{DSS}	30V
R _{DS(on)} (Max.)	38mΩ
I _D	±4.5A
P _D	1.25W

1) Low on - resistance

Features

- 2) Built-in G-S protection diode
- 3) Small surface mount package(TSMT6)
- 4) Pb-free lead plating; RoHS compliant

(1) Drain (6) (5) (4) (2) Drain (3) Gate (4) Source (5) Drain (6) Drain (6) Drain (72 Body Diode (1) (2) (3)

 Packaging specifications

 Packing
 Embossed Tape

 Reel size (mm)
 180

 Tape width (mm)
 8

 Quantity (pcs)
 3000

 Taping code
 TR

Marking

Application

Switching

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V _{DSS}	30	V
Continuous drain current	I _D	±4.5	Α
Pulsed drain current	I _{DP} *1	±18	Α
Gate - Source voltage	V _{GSS}	±20	V
Douger discinction	P _D *2	1.25	W
Power dissipation	P _D *3	0.95	W
Junction temperature	T _j	150	°C
Operating junction and storage temperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Deremeter	Cymphol	Values			Lloit
Parameter	Symbol	Min.	Тур.	Max.	Unit
The word reciptores is unation, ambient	R _{thJA} *2	-	-	100	°C/W
Thermal resistance, junction - ambient	R _{thJA} *3	1	1	132	°C/W

● Electrical characteristics (T_a = 25°C)

Parameter	Symbol Conditions		Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	UTIIL	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I _D = 1mA referenced to 25°C	-	29	-	mV/°C	
Zero gate voltage drain current	I _{DSS}	V _{DS} = 30V, V _{GS} = 0V	-	-	1	μA	
Gate - Source leakage current I _{GSS}		$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±10	μA	
Gate threshold voltage	$V_{GS(th)}$	V _{DS} = 10V, I _D = 1mA	1.0	1	2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_{j}}$	I _D = 1mA referenced to 25°C	-	-1.6	-	mV/°C	
		V _{GS} = 10V, I _D = 4.5A	-	27	38		
Static drain - source on - state resistance	R _{DS(on)} *4	V _{GS} = 4.5V, I _D = 4.5A	-	36	51	mΩ	
		V _{GS} = 4.0V, I _D = 4.5A	-	40	56		
Gate resistance	R _G f = 1MHz, open drain		-	6	-	Ω	
Forward Transfer Admittance	Y _{fs} *4	V _{DS} = 10V, I _D = 4.5A	3.5	-	-	S	

^{*1} Pw \leq 10 μ s , Duty cycle \leq 1%

^{*2} Mounted on a ceramic board (30×30×0.8mm)

^{*3} Mounted on a FR4 (25×25×0.8mm)

^{*4} Pulsed

●Electrical characteristics (T_a = 25°C)

Davarantari	Curahal	Conditions	Values			l leit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	520	-	
Output capacitance C _{oss}		V _{DS} = 10V	-	150	-	pF
Reverse transfer capacitance	C _{rss}	C _{rss} f = 1MHz		95	-	
Turn - on delay time	$t_{d(on)}^{*4}$	V _{DD} ≈ 15V,V _{GS} = 10V	-	12	-	
Rise time	t _r *4	I _D = 2.25A	-	19	-	
Turn - off delay time	t _{d(off)} *4	$R_L \simeq 6.67\Omega$	-	41	-	ns
Fall time	t _f *4	$R_G = 10\Omega$	-	14	-	

• Gate charge characteristics $(T_a = 25^{\circ}C)$

	\ a	,					
Parameter	Cumph of	Conditions	Values			1 1-:4	
raianietei	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Total gate charge	Qg*4	V _{DD} ≃ 15V.	-	6.8	9.5		
Gate - Source charge	Q _{gs} *4	$V_{DD} \approx 15V$, $I_D = 4.5A$,	-	1.6	-	nC	
Gate - Drain charge	Q _{gd} *4	V _{GS} = 5V	-	2.3	-		

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Darameter	Symbol	Conditions	Values			l leit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Continuous forward current	I _S	T - 25°C	-	-	1.0	Α	
Pulse forward current	I _{SP} *1	T _a = 25℃	-	-	18	Α	
Forward voltage	V _{SD} *4	V _{GS} = 0V, I _S = 1.0A	-	-	1.2	V	

Fig.1 Power Dissipation Derating Curve

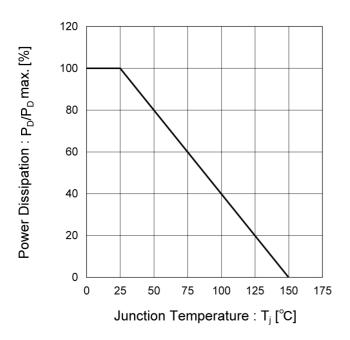
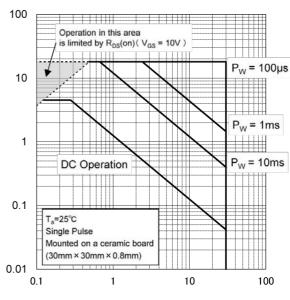


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

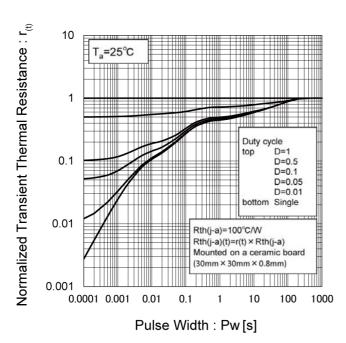
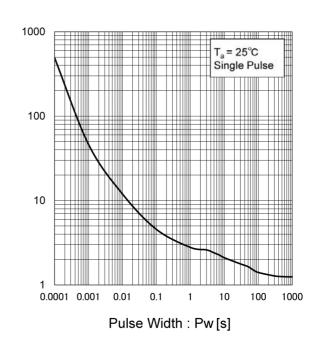
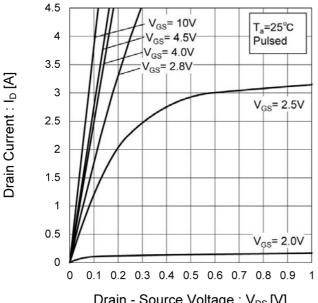


Fig.4 Single Pulse Maximum Power dissipation



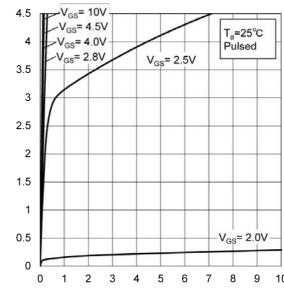
Peak Transient Power : P(W)

Fig.5 Typical Output Characteristics(I)



Drain - Source Voltage : V_{DS} [V]

Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.7 Breakdown Voltage vs. **Junction Temperature**

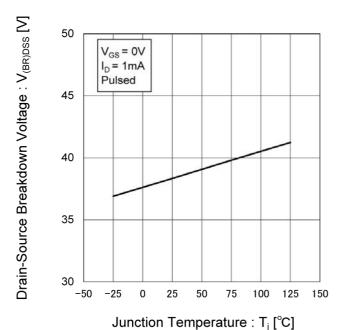


Fig.8 Typical Transfer Characteristics

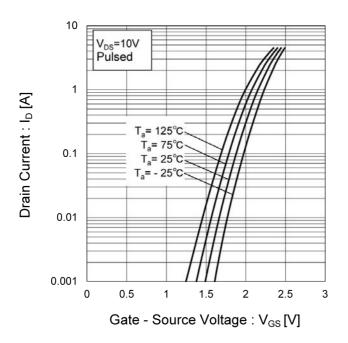


Fig.9 Gate Threshold Voltage vs. Junction Temperature

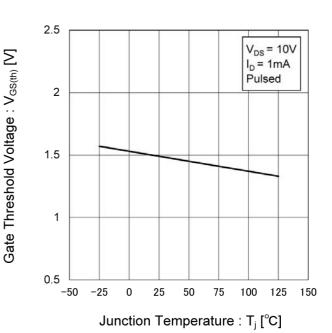


Fig.10 Forward Transfer Admittance vs.
Drain Current

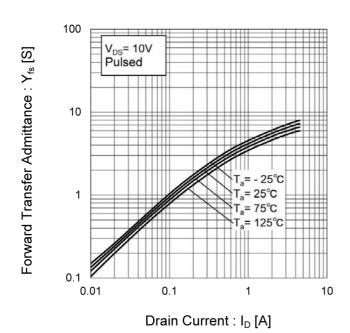


Fig.11 Drain Current Derating Curve

120 100 Drain Current Dissipation 80 : I_D/I_Dmax. [%] 60 40 20 0 -25 0 25 50 75 100 125 150 Junction Temperature : T_j [°C]

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

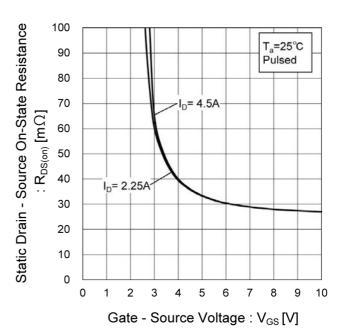


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

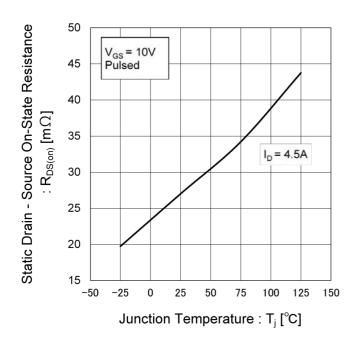


Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)

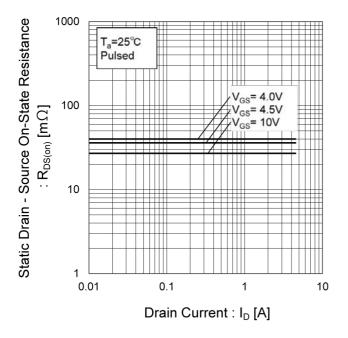


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

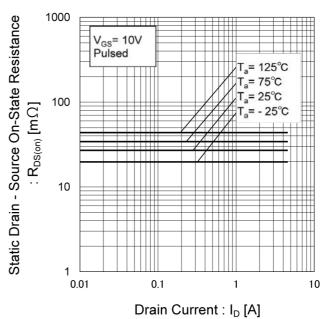


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

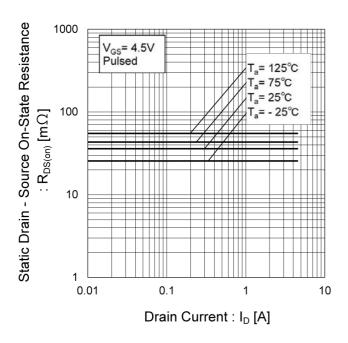


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current (IV)

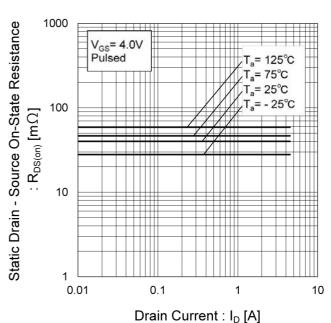


Fig.18 Typical Capacitance vs.

Drain - Source Voltage

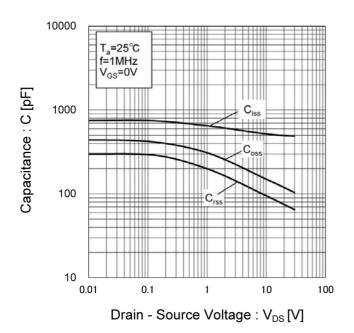


Fig.19 Switching Characteristics

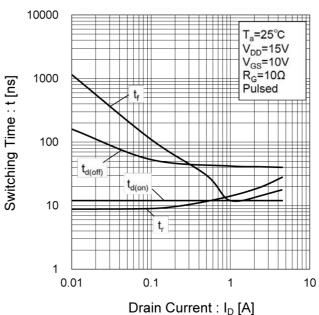


Fig.20 Dynamic Input Characteristics

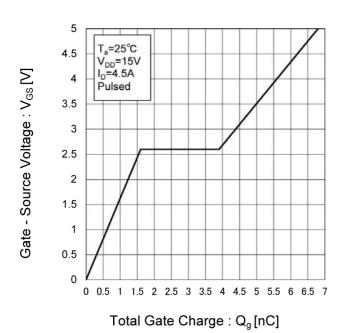
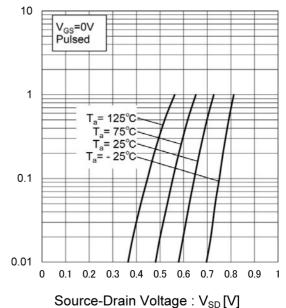


Fig.21 Source Current vs.

Source Drain Voltage



Source Current : Is [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

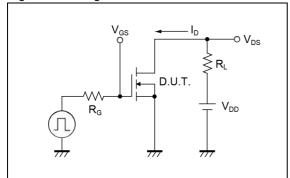


Fig.2-1 Gate Charge Measurement Circuit

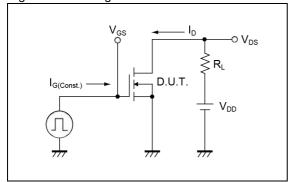


Fig.1-2 Switching Waveforms

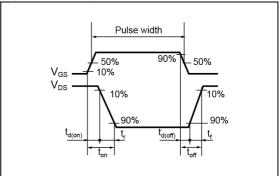
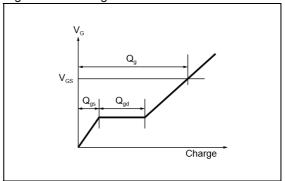


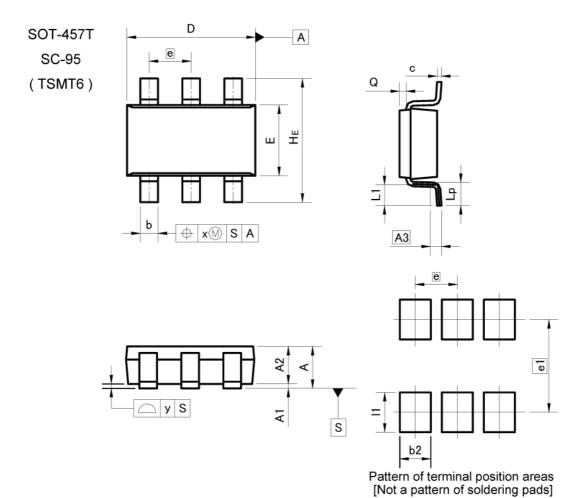
Fig.2-2 Gate Charge Waveform



Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

Dimensions



DIM	MILIM	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
Α	8 2	1.00	=	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.3	25	0.0	10
b	0.35	0.50	0.014	0.020
С	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.9	0.95		37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
x	877	0.20	=	0.008
У	-	0.10		0.004

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2		0.70	-	0.028
e1	2.	2.10		083
11	8 2-	0.90	= :	0.035

Dimension in mm/inches



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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CL ACCTI
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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